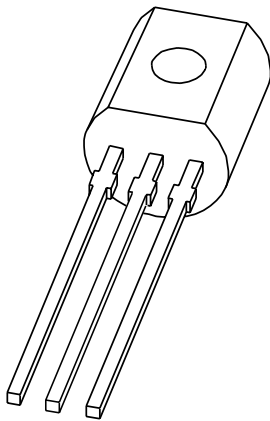


DATA SHEET



BC875; BC879 NPN Darlington transistors

Product specification
Supersedes data of 1999 May 28

2004 Nov 05

NPN Darlington transistors

BC875; BC879

FEATURES

- High DC current gain (min. 1000)
- High current (max. 1 A)
- Low voltage (max. 80 V)
- Integrated diode and resistor.

APPLICATIONS

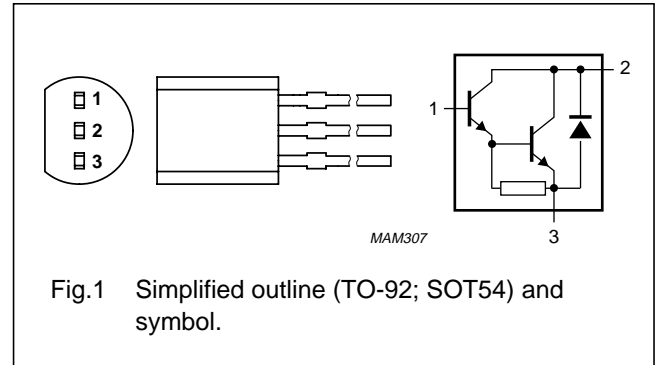
- Relay drivers.

DESCRIPTION

NPN Darlington transistor in a TO-92 (SOT54) plastic package. PNP complement: BC878.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
BC875	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
BC879			

NPN Darlington transistors

BC875; BC879

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	–	60	V
	BC875			100	V
V _{CES}	collector-emitter voltage	V _{BE} = 0 V	–	45	V
	BC875			80	V
V _{EBO}	emitter-base voltage	open collector	–	5	V
I _C	collector current (DC)		–	1	A
I _{CM}	peak collector current		–	2	A
I _B	base current (DC)		–	0.2	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	–	0.83	W
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	150	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

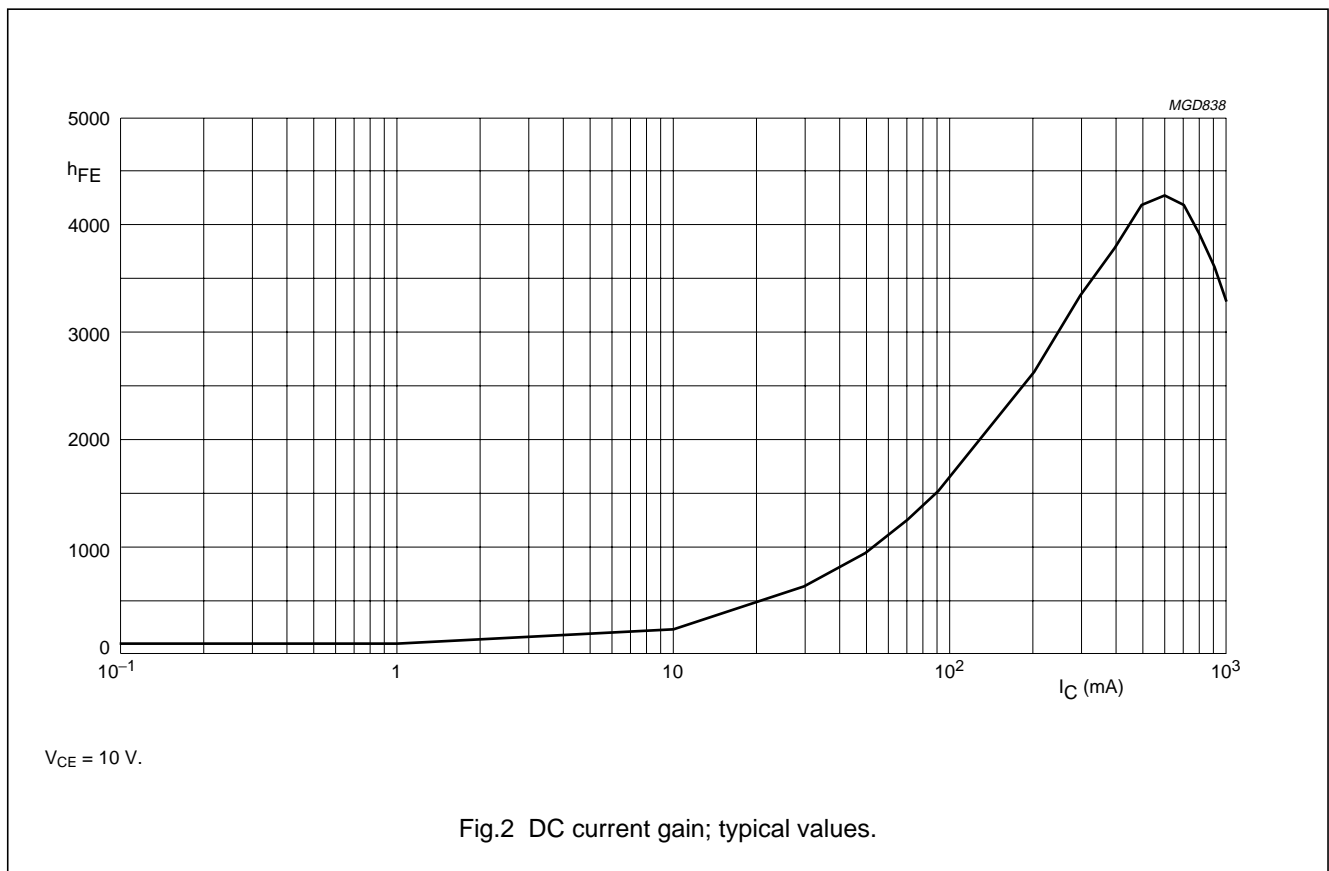
NPN Darlington transistors

BC875; BC879

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	collector-emitter cut-off current	V _{BE} = 0 V	–	–	–	–
	BC875	V _{CE} = 45 V	–	–	50	nA
	BC879	V _{CE} = 80 V	–	–	50	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 4 V; I _C = 0 A	–	–	50	nA
h _{FE}	DC current gain	V _{CE} = 10 V; see Fig.2	–	–	–	–
		I _C = 150 mA	1000	–	–	–
		I _C = 0.5 A	2000	–	–	–
V _{CEsat}	collector-emitter saturation voltage	I _C = 0.5 A; I _B = 0.5 mA	–	–	1.3	V
		I _C = 1 A; I _B = 1 mA	–	–	1.8	V
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 1 mA	–	–	2.2	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 0.5 A; f = 100 MHz	–	200	–	MHz
Switching times (between 10% and 90% levels)						
t _{on}	turn-on time	I _{Con} = 500 mA; I _{Bon} = 0.5 mA;	–	500	–	ns
t _{off}	turn-off time	I _{Boff} = –0.5 mA	–	1300	–	ns



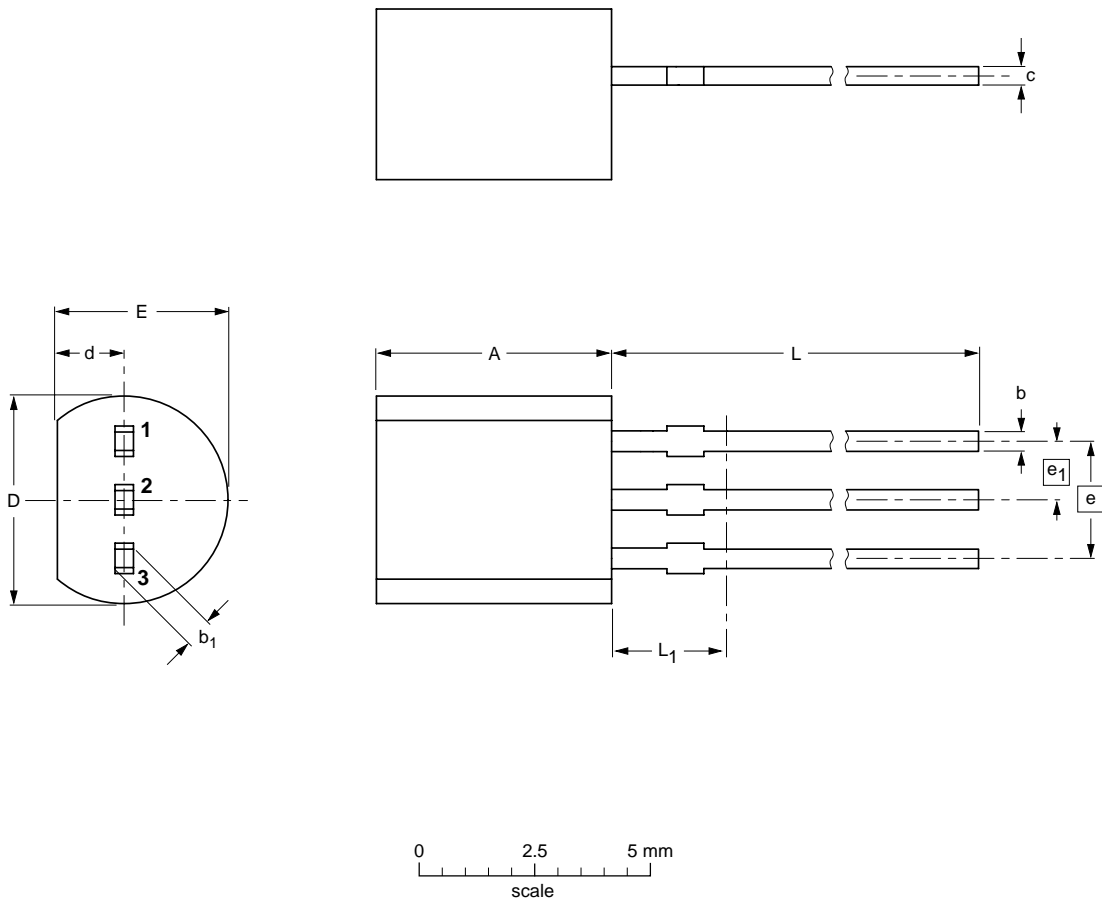
NPN Darlington transistors

BC875; BC879

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	c	D	d	E	e	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT54		TO-92	SC-43A		-97-02-28 04-06-28

NPN Darlington transistors

BC875; BC879

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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